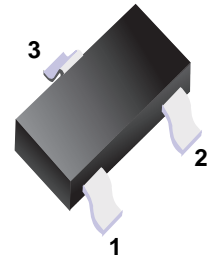


■ NPN Transistors

■ Features

- Small Package
- Complementary to MMBT2907AT



1.Base  
2.Emitter  
3.Collector

■ Simplified outline(SOT-523)

■ Absolute Maximum Ratings Ta = 25°C

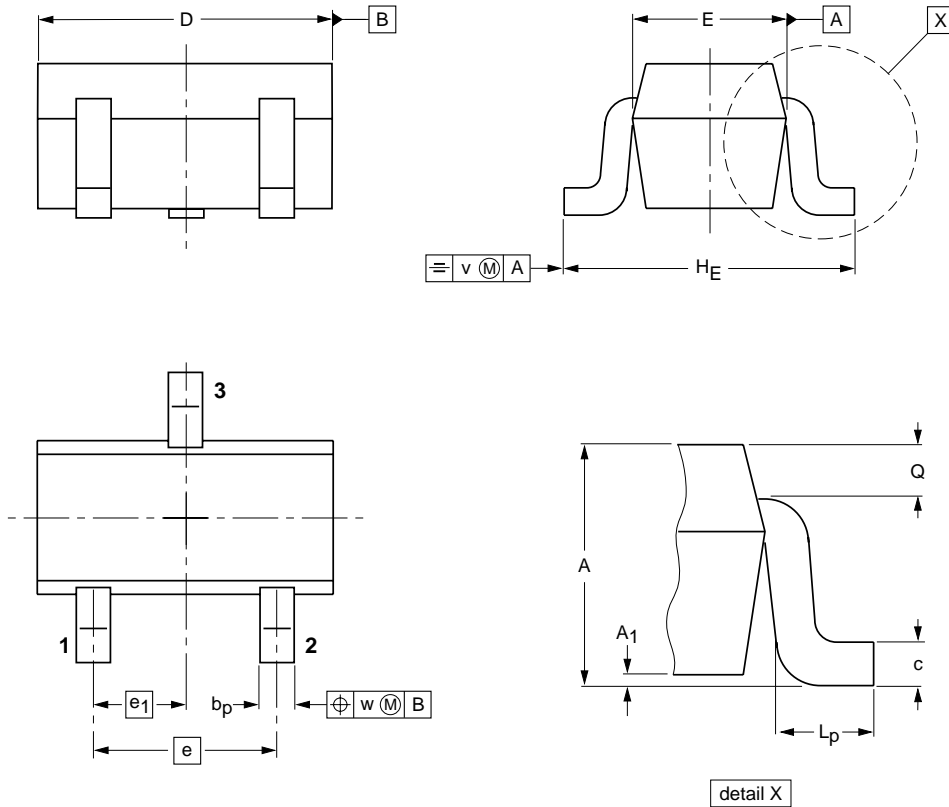
Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V <sub>CB0</sub>	75	V
Collector - Emitter Voltage	V <sub>CEO</sub>	40	
Emitter - Base Voltage	V <sub>EBO</sub>	6	
Collector Current - Continuous	I <sub>c</sub>	600	mA
Collector Power Dissipation	P <sub>c</sub>	150	mW
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	833	°C/W
Junction Temperature	T <sub>J</sub>	150	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to 150	

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector- base breakdown voltage	V <sub>CB0</sub>	I <sub>c</sub> = 100 μA, I <sub>E</sub> = 0	75			V
Collector- emitter breakdown voltage	V <sub>CEO</sub>	I <sub>c</sub> = 10 mA, I <sub>B</sub> = 0	40			
Emitter - base breakdown voltage	V <sub>EBO</sub>	I <sub>E</sub> = 100 μA, I <sub>C</sub> = 0	6			
Collector-base cut-off current	I <sub>CB0</sub>	V <sub>CB</sub> = 75 V, I <sub>E</sub> = 0			100	nA
Collector cut-off current	I <sub>CEx</sub>	V <sub>CE</sub> = 60 V, V <sub>EB(off)</sub> =3V			100	
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 6V, I <sub>C</sub> =0			100	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =150 mA, I <sub>B</sub> =15mA			0.3	V
		I <sub>C</sub> = 500 mA, I <sub>B</sub> = 50mA			1	
Base - emitter saturation voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =150 mA, I <sub>B</sub> =15mA			1.2	
		I <sub>C</sub> = 500 mA, I <sub>B</sub> = 50mA			2	
DC current gain	h <sub>FE(1)</sub>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 0.1mA	35			
	h <sub>FE(2)</sub>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 1mA	50			
	h <sub>FE(3)</sub>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 10mA	75			
	h <sub>FE(4)</sub>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 150mA	100		300	
	h <sub>FE(5)</sub>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 500mA	40			
Delay time	t <sub>d</sub>	V <sub>CC</sub> =30V, V <sub>BE(off)</sub> =-0.5V I <sub>C</sub> =150mA, I <sub>B1</sub> =15mA			10	nS
Rise time	t <sub>r</sub>				25	
Storage time	t <sub>s</sub>				225	
Fall time	t <sub>f</sub>				60	
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f=1MHz			8	pF
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 20V, I <sub>C</sub> = 20mA, f=100MHz	300			MHz

**Package Outline**

**SOT-523**



**DIMENSIONS (mm are the original dimensions)**

UNIT	A	A <sub>1</sub> max	b <sub>p</sub>	c	D	E	e	e <sub>1</sub>	H <sub>E</sub>	L <sub>p</sub>	Q	v	w
mm	0.95 0.60	0.1	0.30 0.15	0.25 0.10	1.8 1.4	0.9 0.7	1	0.5	1.75 1.45	0.45 0.15	0.23 0.13	0.2	0.2

**Summary of Packing Options**

Package	Packing Description	Packing Quantity	Industry Standard
SOT-523	Tape/Reel, 7" reel	3000	EIA-481-1